

FAST CMOS 16-BIT BIDIRECTIONAL TRANSCEIVER

IDT54/74FCT16245T/AT/CT/ET

FEATURES:

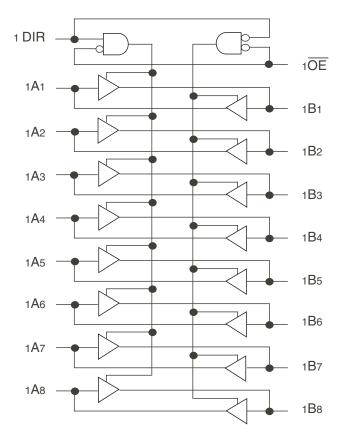
- 0.5 MICRON CMOS Technology
- · High-speed, low-power CMOS replacement for ABT functions
- Typical tsk(0) (Output Skew) < 250ps
- Low input and output leakage ≤ 1µA (max.)
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- High drive outputs (-32mA IOH, 64mA IOL)
- · Power off disable outputs permit "live insertion"
- Typical VOLP (Output Ground Bounce) < 1.0V at Vcc = 5V, TA = 25°C
- · Available in the following packages:
 - Industrial: SSOP, TSSOP
 - Military: CERPACK

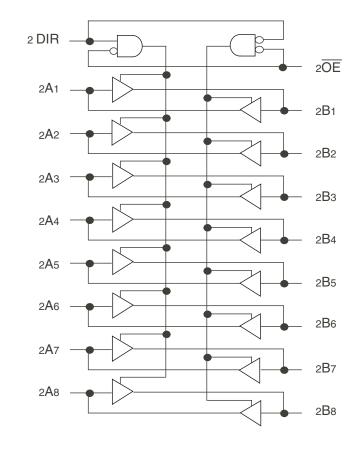
FUNCTIONAL BLOCK DIAGRAM

DESCRIPTION:

The FCT16245T16-bit transceiver is built using advanced dual metal CMOS technology. These high-speed, low-power transceivers are ideal for synchronous communication between two busses (A and B). The Direction and Output Enable controls operate these devices as either two independent 8-bit transceivers or one 16-bit transceiver. The direction control pin (xDIR) controls the direction of data flow. The output enable pin ($x\overline{OE}$) overrides the direction control and disables both ports. All inputs are designed with hysteresis for improved noise margin.

The FCT16245T is ideally suited for driving high-capacitance loads and lowimpedance backplanes. The output buffers are designed with power off disable capability to allow "live insertion" of boards when used as backplane drivers.



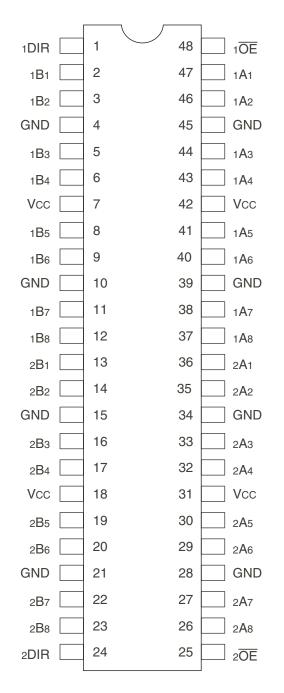


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MILITARY AND INDUSTRIAL TEMPERATURE RANGES

JANUARY 2009

PIN CONFIGURATION



SSOP/ TSSOP CERPACK TOP VIEW

MILITARY AND INDUSTRIAL TEMPERATURE RANGES

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to +7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-60 to +120	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. All device terminals except FCT162XXXT and FCT166XXXT (APort) Output and I/O terminals.

3. Output and I/O terminals terminals for FCT162XXX and FCT166XXXT (A-Port).

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
Cin	Input Capacitance	VIN = 0V	3.5	6	pF
Соит	Output Capacitance	Vout = 0V	3.5	8	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description			
xOE Output Enable Inputs (Active LOW)				
xDIR	DIR Direction Control Inputs			
x A x Side A Inputs or 3-State Outputs				
x B x Side B Inputs or 3-State Outputs				

FUNCTION TABLE(1)

Inputs		
xOE	xDIR	Outputs
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	Х	High Z State

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = 5.0V $\pm 10\%$; Military: TA = -55° C to $+125^{\circ}$ C, VCC = 5.0V $\pm 10\%$

Symbol	Parameter	Test Conditions ⁽¹⁾			Тур. ⁽²⁾	Max.	Unit
Viн	Input HIGH Level	Guaranteed Logic HIGH Level		2	_	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		_	—	0.8	V
Ін	Input HIGH Current (Input pins) ⁽⁵⁾	Vcc = Max.	VI = VCC	-	_	±1	μA
	Input HIGH Current (I/O pins) ⁽⁵⁾			_	—	±1	
١ıL	Input LOW Current (Input pins) ⁽⁵⁾		VI = GND	_	_	±1	
	Input LOW Current (I/O pins) ⁽⁵⁾			_	—	±1	
Іоzн	High Impedance Output Current	Vcc = Max.	Vo = 2.7V	_	_	±1	μA
Iozl	(3-State Output pins) ⁽⁵⁾		Vo = 0.5V	_	_	±1	
Vik	Clamp Diode Voltage	Vcc = Min., IIN = -18mA		-	-0.7	-1.2	V
los	Short Circuit Current	Vcc = Max., Vo = GND ⁽³⁾	Vcc = Max., Vo = GND ⁽³⁾		-140	-250	mA
Vн	Input Hysteresis	_		_	100	_	mV
ІССL ІССН ІССZ	Quiescent Power Supply Current	Vcc = Max. Vin = GND or Vcc		—	5	500	μA

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Тур. ⁽²⁾	Max.	Unit
lo	Output Drive Current	Vcc = Max., Vo = 2.5	V ⁽³⁾	-50	_	-180	mA
Vон	Output HIGH Voltage	Vcc = Min.	Юн = −3mА,	-2.5	3.5	_	V
		VIN = VIH or VIL	Iон = –12mA MIL	2.4	3.5	—	V
			Iон = -15mA IND				
			Iон = –24mA MIL	2	3	_	V
			$IOH = -32mA IND^{(4)}$				
Vol	Output LOW Voltage	Vcc = Min.	Iol = 48mA MIL	-	0.2	0.55	V
		VIN = VIH or VIL	Iol = 64mA IND				
IOFF	Input/Output Power Off Leakage ⁽⁵⁾	VCC = 0V, VIN or VO ≤ 4	4.5V	_	_	±1	μA

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

4. Duration of the condition can not exceed one second.

5. The test limit for this parameter is $\pm 5\mu A$ at TA = $-55^{\circ}C$.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditi	ons ⁽¹⁾	Min.	Тур.(2)	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	VCC = Max. $VIN = 3.4V^{(3)}$		—	0.5	1.5	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open xOE = xDIR = GND One Input Togging 50% Duty Cycle	VIN = VCC VIN = GND	_	60	100	μΑ/ MHz
IC	Total Power Supply Current ⁽⁶⁾	Vcc = Max. Outputs Open fi = 10MHz	VIN = VCC VIN = GND		0.6	1.5	mA
		50% Duty Cycle xOE = xDIR = GND One Bit Toggling	VIN = 3.4V VIN = GND		0.9	2.3	
		Vcc = Max. Outputs Open fi = 2.5MHz 50% Duty Cycle	VIN = VCC VIN = GND	—	2.4	4.5 ⁽⁵⁾	
		xOE = xDIR = GND Sixteen BitsTogging	VIN = 3.4V VIN = GND	_	6.4	16.5 ⁽⁵⁾	

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input (VIN = 3.4V). All other inputs at Vcc or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.

6. IC = IQUIESCENT + INPUTS + IDYNAMIC

IC = ICC + Δ ICC DHNT + ICCD (fCPNCP/2 + fiNi)

Icc = Quiescent Current (IccL, IccH and Iccz)

 ΔIcc = Power Supply Current for a TTL High Input (VIN = 3.4V)

DH = Duty Cycle for TTL Inputs High

NT = Number of TTL Inputs at DH

ICCD = Dynamic Current caused by an Input Transition Pair (HLH or LHL)

fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)

NCP = Number of Clock Inputs at fCP

fi = Input Frequency

Ni = Number of Inputs at fi

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - INDUSTRIAL

			74FCT16245AT 74FCT16245CT 74FCT162		6245ET				
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 50pF	1.5	4.6	1.5	4.1	1.5	3.2	ns
t PHL	A to B, B to A	RL= 500Ω							
t PZH	Output Enable Time		1.5	6.2	1.5	5.8	1.5	4.4	ns
tPZL	xOE to A or B								
tphz	Output Disable Time		1.5	5	1.5	4.8	1.5	4	ns
tPLZ	xOE to A or B								
t PZH	Output Enable Time		1.5	6.2	1.5	5.8	1.5	4.8	ns
tPZL	xDIR to A or B ⁽⁴⁾								
t PHZ	Output Disable Time		1.5	5	1.5	4.8	1.5	4	ns
tPZL	xDIR to A or B ⁽⁴⁾								
tSK(o)	Output Skew ⁽³⁾		—	0.5	—	0.5	_	0.5	ns

SWITCHING CHARACTERISTICS OVER OPERATING RANGE - MILITARY

			54FCT	16245T	54FCT1	6245AT	54FCT1	6245CT	
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 50pF	1.5	7.5	1.5	4.9	1.5	4.5	ns
t PHL	A to B, B to A	RL= 500Ω							
tрzн	Output Enable Time		1.5	10	1.5	6.5	1.5	6.2	ns
tPZL	xOE to A or B								
tPHZ	Output Disable Time		1.5	10	1.5	6	1.5	5.2	ns
tPLZ	xOE to A or B								
tРZH	Output Enable Time		1.5	10	1.5	6.5	1.5	6.2	ns
tPZL	xDIR to A or B ⁽⁴⁾								
tPHZ	Output Disable Time	1	1.5	10	1.5	6	1.5	5.2	ns
tPZL	xDIR to A or B ⁽⁴⁾								
tsk(o)	Output Skew ⁽³⁾]	_	0.5	-	0.5	_	0.5	ns

NOTES:

1. See test circuit and waveforms.

2. Minimum limits are guaranteed but not tested on Propagation Delays.

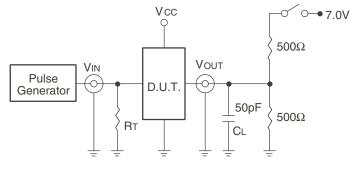
3. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

4. This limit is guaranteed but not tested.

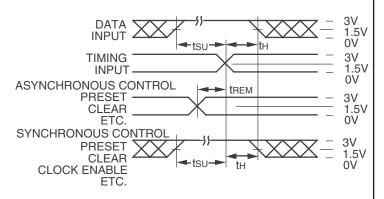
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MILITARY AND INDUSTRIAL TEMPERATURE RANGES

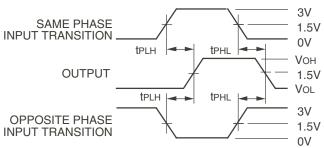
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-up, Hold, and Release Times





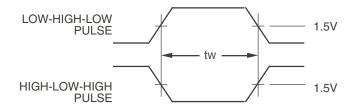
SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

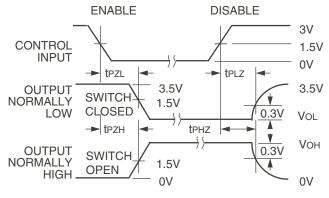
DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



Pulse Width

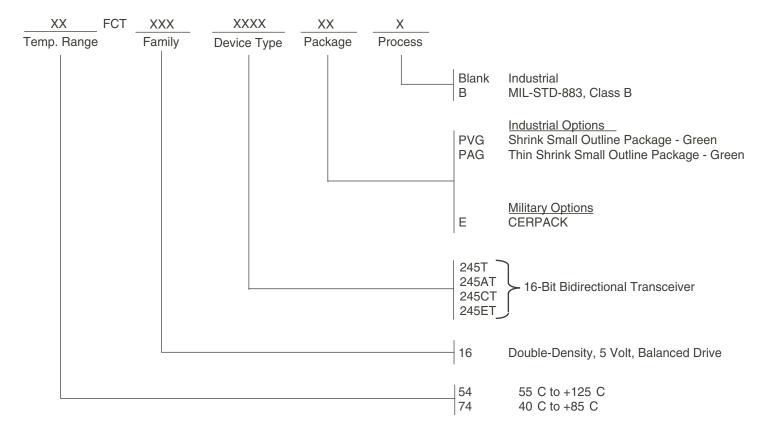




NOTES:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH. 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tF \leq 2.5ns; tR \leq 2.5ns.

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